

	Type	Hits	Search Text	DBs
1	BRS	24515	plasma with nitrid\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
2	BRS	84	S1 and ("5" adj ev)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
3	BRS	18	S2 and (electron adj energy)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
4	BRS	5065	S1 and (plasma with nitrogen)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB

	Type	Hits	Search Text	DBs
5	BRS	491	S4 and ev	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
6	BRS	357	(silicon with oxide with dielectric) and (solution with oxidation)	USPAT
7	BRS	3	S6 and (nitric adj acid) and (perchloric adj acid)	USPAT
8	BRS	692	(silicon with oxidation with acid)	USPAT
9	BRS	100	S8 and (gate with dielectric)	USPAT
10	BRS	17	S9 and (nitric or perchloric)	USPAT
11	BRS	1196	wet with oxidation with silicon	USPAT
12	BRS	0	S11 and (nitric and perchloric) and (gate with electrode)	USPAT

	Type	Hits	Search Text	DBs
13	BRS	33	S11 and nitric and (gate with electrode)	USPAT
14	BRS	71	S6 and (nitric with acid)	USPAT
15	BRS	165	silicon with oxide with oxidizer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
16	BRS	1	S15 and nitric and perchloric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
17	BRS	1	S15 and perchloric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB

	Type	Hits	Search Text	DBs
18	BRS	20	S15 and nitric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
19	BRS	9	(gate adj oxide) with (nitric adj acid)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
20	BRS	1414	(silicon with oxidation with acid)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
21	BRS	297	S20 and (gate adj oxide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB

	Type	Hits	Search Text	DBs
22	BRS	29	S21 and (nitric adj acid)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
23	BRS	2699	plasma and (electron with temperature) and (electron with energy)	USPAT
24	BRS	42	S23 and nitridation	USPAT
25	BRS	235	plasma and (electron adj temperature) and (electron adj energy)	USPAT
26	BRS	5	S25 and nitridation	USPAT
27	BRS	1744	(low adj energy) with plasma	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB

	Type	Hits	Search Text	DBs
28	BRS	107	S27 and (silicon with oxynitride)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
29	BRS	24	S28 and ev	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
30	BRS	81	S27 and (silicon with nitrogen) and ev	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
31	BRS	5	S27 and (silicon with nitrogen) and ("5" adj ev)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB

	Type	Hits	Search Text	DBs
32	BRS	0	relationship with ((electron adj temperature) and (electron adj energy)) with plasma	USPAT
33	BRS	96	((electron adj temperature) and (electron adj energy)) with plasma	USPAT
34	BRS	26	S33 and silicon and nitrogen	USPAT
35	BRS	3	very adj low adj energy adj plasma	US-PGPUB; USPAT
36	BRS	84	(electron adj temperature) with (electron adj energy)	US-PGPUB; USPAT
37	BRS	7	S36 and (plasma with nitrogen)	US-PGPUB; USPAT
38	BRS	115	CMOS and ((gate with dielectric) with different with thickness)	USPAT
39	BRS	596	438/199,216,240,287,775,786-788.cccls. and (plasma with nitrogen)	US-PGPUB; USPAT

	Type	Hits	Search Text	DBs
40	BRS	30	S39 and (electron with energy)	US-PGPUB; USPAT
41	BRS	14	S40 and ev	US-PGPUB; USPAT
42	BRS	24540	plasma with nitrid\$5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB